

ST1803DHI

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

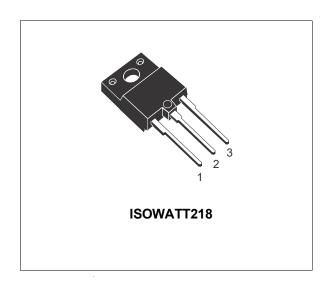
- NEW SERIES, ENHANCED PERFORMANCE
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING
- INTEGRATED FREE WHEELING DIODE
- HIGH VOLTAGE CAPABILITY (> 1500 V)
- HIGH SWITCHING SPEED
- TIGTHER hfe CONTROL
- IMPROVED RUGGEDNESS

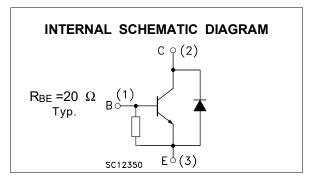
APPLICATIONS:

 HORIZONTAL DEFLECTION FOR COLOR TVS

DESCRIPTION

The ST1803DHI is manufactured using Diffused Collector technology for more stable operation Vs base drive circuit variations resulting in very low worst case dissipation.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)	1500	V
V_{CEO}	Collector-Emitter Voltage (I _B = 0)	600	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)	7	V
Ic	Collector Current	10	А
I _{CM}	Collector Peak Current (t _p < 5 ms)	15	Α
lΒ	Base Current	4	Α
P _{tot}	Total Dissipation at T _c = 25 °C	50	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500	V
T _{stg}	Storage Temperature	-65 to 150	°C
T _i	Max. Operating Junction Temperature	150	°C

December 2002 1/6

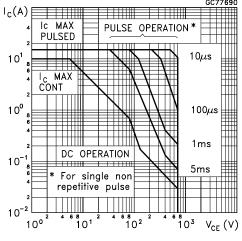
THERMAL DATA

ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ °C unless otherwise specified)

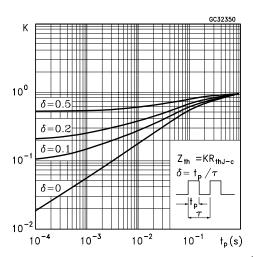
Symbol	Parameter	Tes	t Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = 1500 V V _{CE} = 1500 V	T _j = 125 °C			1 2	mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 4 V		130		400	mA
V _{(BR)EBO}	Emitter-Base Breakdown Voltage (I _C = 0)	I _E = 700 mA		7			V
$V_{CE(sat)^*}$	Collector-Emitter Saturation Voltage	I _C = 4 A I _C = 4 A	$I_B = 0.8 A$ $I_B = 1.2 A$		3	5 1.5	V V
V _{BE(sat)*}	Base-Emitter Saturation Voltage	I _C = 4 A	I _B = 0.8 A			1.2	V
h _{FE} *	DC Current Gain	I _C = 1 A I _C = 4.5 A I _C = 4.5 A		10 5	15 5	20 9	
V _F	Diode Forward Voltage	I _F = 5 A			1.5	2	V
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time	I _C = 4 A L _B = 5 μH f = 16 KHz	$I_{Bon(END)} = 0.8 A$ $V_{BB} = -2.5 V$ (see figure 1)		2.7 0.3	4 0.6	μs μs

^{*} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

Safe Operating Area

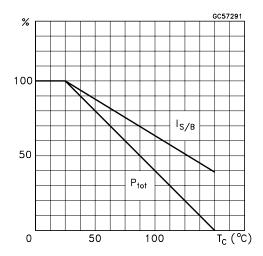


Thermal Impedance

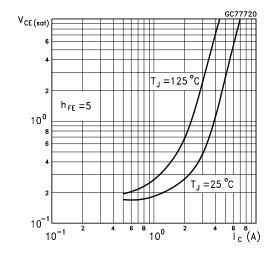


2/6

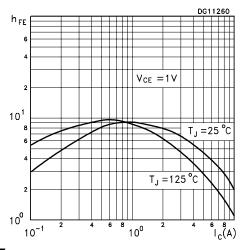
Derating Curve



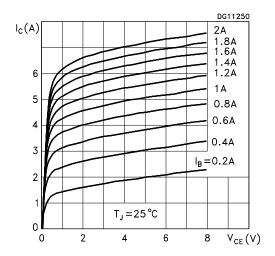
Collector Emitter Saturation Voltage



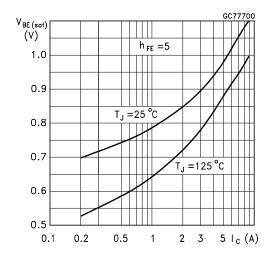
DC Current Gain



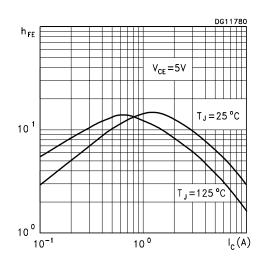
Output Characteristics



Base Emitter Saturation Voltage

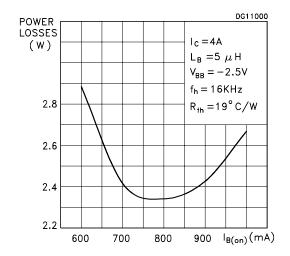


DC Current Gain

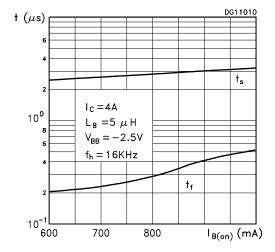


477

Power Losses



Switching Time Inductive Load



Reverse Biased SOA

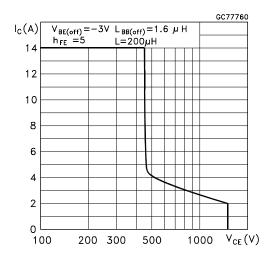
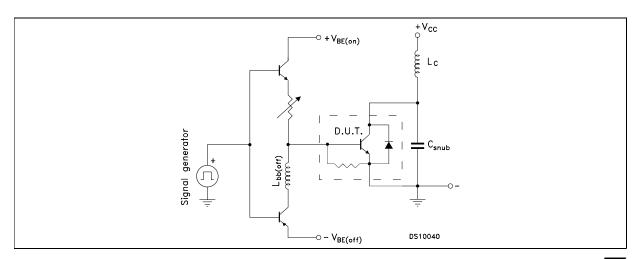


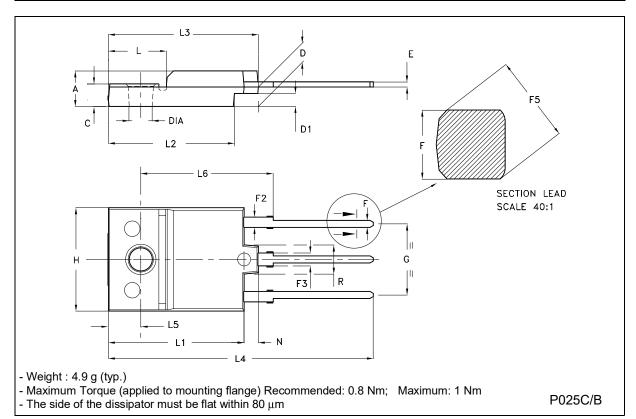
Figure 1: Inductive Load Switching Test Circuit.



4/6

ISOWATT218 NARROW LEADS MECHANICAL DATA

DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	5.35		5.65	0.211		0.222
С	3.30		3.80	0.130		0.150
D	2.90		3.10	0.114		0.122
D1	1.88		2.08	0.074		0.082
E	0.75		0.95	0.030		0.037
F	0.75		0.95	0.030		0.037
F2	1.50		1.70	0.059		0.067
F3	1.90		2.10	0.075		0.083
F5			1.10			0.043
G	10.80		11.20	0.425		0.441
Н	15.80		16.20	0.622		0.638
L		9			0.354	
L1	20.80		21.20	0.819		0.835
L2	19.10		19.90	0.752		0.783
L3	22.80		23.60	0.898		0.929
L4	40.50		42.50	1.594	· ·	1.673
L5	4.85		5.25	0.191		0.207
L6	20.25		20.75	0.797		0.817
N	2.1		2.3	0.083		0.091
R		4.6			0.181	_
DIA	3.5		3.7	0.138		0.146



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics

© 2002 STMicroelectronics – Printed in Italy – All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

http://www.st.com

6/6